**ON Semiconductor** 

Is Now

# Onsemi

To learn more about onsemi<sup>™</sup>, please visit our website at <u>www.onsemi.com</u>

onsemi and ONSEMI. and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product factures, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and asfety requirements or standards, regardless of any support or applications information provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or by customer's technical experts. onsemi products and actal performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use onsemi products for any such unintended or unauthorized application, Buyer shall indemnify and hold onsemi and its officers, employees, subsidiari

## Single Buffer, Non-Inverting, TTL Level

## **TTL-Compatible Inputs**

The NLU1GT50 MiniGate<sup>™</sup> is an advanced CMOS high-speed non-inverting buffer in ultra-small footprint.

The device input is compatible with TTL-type input thresholds and the output has a full 5.0 V CMOS level output swing.

The NLU1GT50 input and output structures provide protection when voltages up to 7.0 V are applied, regardless of the supply voltage.

#### Features

- Designed for 1.65 to 5.5 V V<sub>CC</sub> Operation
- High Speed:  $t_{PD} = 3.5 \text{ ns} (Typ) @ V_{CC} = 5.0 \text{ V}$
- Low Power Dissipation:  $I_{CC} = 1 \mu A$  (Max) at  $T_A = 25^{\circ}C$
- TTL-Compatible Input:  $V_{IL} = 0.8 \text{ V}$ ;  $V_{IH} = 2.0 \text{ V}$ ,  $V_{CC} = 5.0 \text{ V}$
- CMOS–Compatible Output:  $V_{OH} > 0.8 V_{CC}$ ;  $V_{OL} < 0.1 V_{CC}$  @ Load
- Power Down Protection Provided on inputs
- Balanced Propagation Delays
- Ultra-Small Packages
- These are Pb-Free Devices

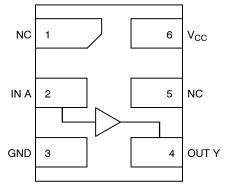


Figure 1. Pinout (Top View)



Figure 2. Logic Symbol

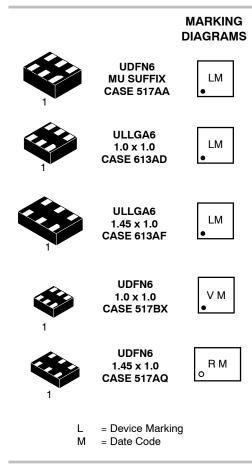
| FUNCTION TABLE |   |  |  |  |
|----------------|---|--|--|--|
| Α              | Y |  |  |  |
| L              | L |  |  |  |
| Н              | Н |  |  |  |

| PIN ASSIGNMENT |                 |  |  |  |
|----------------|-----------------|--|--|--|
| 1              | NC              |  |  |  |
| 2              | IN A            |  |  |  |
| 3              | GND             |  |  |  |
| 4              | OUT Y           |  |  |  |
| 5              | NC              |  |  |  |
| 6              | V <sub>CC</sub> |  |  |  |



## **ON Semiconductor®**

www.onsemi.com



#### ORDERING INFORMATION

See detailed ordering and shipping information on page 4 of this data sheet.

#### MAXIMUM RATINGS

| Symbol           | Parameter  | Value                  | Unit |
|------------------|--|------------------------|------|
| V <sub>CC</sub>  | DC Supply Voltage  | -0.5 to +7.0           | V    |
| V <sub>IN</sub>  | DC Input Voltage   | -0.5 to +7.0           | V    |
| V <sub>OUT</sub> | DC Output Voltage  | -0.5 to +7.0           | V    |
| Ι <sub>ΙΚ</sub>  | DC Input Diode Current V <sub>IN</sub> < GND   | -20                    | mA   |
| I <sub>OK</sub>  | DC Output Diode Current V <sub>OUT</sub> < GND   | ±20                    | mA   |
| Ι <sub>Ο</sub>   | DC Output Source/Sink Current  | ±12.5                  | mA   |
| I <sub>CC</sub>  | DC Supply Current Per Supply Pin   | ±25                    | mA   |
| I <sub>GND</sub> | DC Ground Current per Ground Pin   | ±25                    | mA   |
| T <sub>STG</sub> | Storage Temperature Range  | -65 to +150            | °C   |
| ΤL               | Lead Temperature, 1 mm from Case for 10 Seconds  | 260                    | °C   |
| TJ               | Junction Temperature Under Bias  | 150                    | °C   |
| MSL              | Moisture Sensitivity   | Level 1                |      |
| F <sub>R</sub>   | Flammability Rating Oxygen Index: 28 to 34   | UL 94 V-0 @ 0.125 in   |      |
| V <sub>ESD</sub> | ESD Withstand Voltage Human Body Model (Note 2)<br>Machine Model (Note 3)<br>Charged Device Model (Note 4) | > 2000<br>> 200<br>N/A | V    |
| ILATCHUP1        | Latchup Performance Above $V_{CC}$ and Below GND at 125 $^\circ C$ (Note 5)                                | ±500                   | mA   |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected. 1. Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2 ounce copper trace no air flow.

2. Tested to EIA / JESD22-A114-A.

Tested to EIA / JESD22-A115-A.
 Tested to JESD22-C101-A.

5. Tested to EIA / JESD78.

#### **RECOMMENDED OPERATING CONDITIONS**

| Symbol              | Parameter  |                |        | Max       | Unit |
|---------------------|--|----------------|--------|-----------|------|
| V <sub>CC</sub>     | Positive DC Supply Voltage   |                | 1.65   | 5.5       | V    |
| V <sub>IN</sub>     | Digital Input Voltage  |                | 0      | 5.5       | V    |
| V <sub>OUT</sub>    | Output Voltage   |                | 0      | 5.5       | V    |
| T <sub>A</sub>      | Operating Free-Air Temperature   |                | -55    | +125      | °C   |
| $\Delta t/\Delta V$ | Input Transition Rise or Fall Rate $V_{CC} = 3.3 V \pm V_{CC} = 5.0 V \pm 1000 V_{CC} = 5.0 $ | 0.3 V<br>0.5 V | 0<br>0 | 100<br>20 | ns/V |

#### DC ELECTRICAL CHARACTERISTICS

|                  |                                |  |                     | т,                        | ς = 25 ° | с                         | T <sub>A</sub> = +85°C    |                           | T <sub>A</sub> = −55°C to<br>+125°C |                           |      |
|------------------|--------------------------------|--|---------------------|---------------------------|----------|---------------------------|---------------------------|---------------------------|-------------------------------------|---------------------------|------|
| Symbol           | Parameter                      | Conditions   | V <sub>CC</sub> (V) | Min                       | Тур      | Мах                       | Min                       | Max                       | Min                                 | Max                       | Unit |
| V <sub>IH</sub>  | Low-Level<br>Input<br>Voltage  |  | 1.65 to<br>2.29     | 0.50 x<br>V <sub>CC</sub> |          |                           | 0.50 x<br>V <sub>CC</sub> |                           |                                     |                           | V    |
|                  | vollage                        |  | 2.3 to 2.99         | 0.45 x<br>V <sub>CC</sub> |          |                           | 0.45 x<br>V <sub>CC</sub> |                           |                                     |                           |      |
|                  |                                |  | 3.0                 | 1.4                       |          |                           | 1.4                       |                           |                                     |                           |      |
|                  |                                |  | 4.5 to 5.5          | 2.0                       |          |                           | 2.0                       |                           |                                     |                           |      |
| V <sub>IL</sub>  | Low–Level<br>Input<br>Voltage  |  | 1.65 to<br>2.29     |                           |          | 0.10 x<br>V <sub>CC</sub> |                           | 0.10 x<br>V <sub>CC</sub> |                                     | 0.10 x<br>V <sub>CC</sub> | V    |
|                  | voltage                        |  | 2.3 to 2.99         |                           |          | 0.15 x<br>V <sub>CC</sub> |                           | 0.15 x<br>V <sub>CC</sub> |                                     | 0.15 x<br>V <sub>CC</sub> |      |
|                  |                                |  | 3.0                 |                           |          | 0.53                      |                           | 0.53                      |                                     | 0.53                      |      |
|                  |                                |  | 4.5 to 5.5          |                           |          | 0.8                       |                           | 0.8                       |                                     | 0.8                       |      |
| V <sub>OH</sub>  | Output                         | $V_{IN} = V_{IH} \text{ or } V_{IL}$   | 1.65 to<br>2.99     | V <sub>CC</sub> -<br>0.1  |          |                           | V <sub>CC</sub> -<br>0.1  |                           | V <sub>CC</sub> -<br>0.1            |                           | V    |
| Voltage          | I <sub>OH</sub> = -50 μA       | 3.0  | 2.9                 | 3.0                       |          | 2.9                       |                           | 2.9                       |                                     |                           |      |
|                  |                                | 4.5  | 4.4                 | 4.5                       |          | 4.4                       |                           | 4.4                       |                                     |                           |      |
|                  |                                | $V_{IN} = V_{IH} \text{ or } V_{IL}$<br>$I_{OH} = -4 \text{ mA}$<br>$I_{OH} = -8 \text{ mA}$ | 3.0<br>4.5          | 2.58<br>3.94              |          |                           | 2.48<br>3.80              |                           | 2.34<br>3.66                        |                           |      |
| V <sub>OL</sub>  | Low-Level<br>Output<br>Voltage | $V_{IN}$ = $V_{IH}$ or $V_{IL}$<br>$I_{OL}$ = 50 $\mu$ A                                     | 1.65 to<br>2.99     |                           | 0        | 0.1                       |                           | 0.1                       |                                     | 0.1                       | V    |
|                  | vollage                        |  | 3.0                 |                           | 0        | 0.1                       |                           | 0.1                       |                                     | 0.1                       |      |
|                  |                                |  | 4.5                 |                           | 0        | 0.1                       |                           | 0.1                       |                                     | 0.1                       |      |
|                  |                                | $V_{IN} = V_{IH} \text{ or } V_{IL}$<br>$I_{OL} = 4 \text{ mA}$<br>$I_{OL} = 8 \text{ mA}$   | 3.0<br>4.5          |                           |          | 0.36<br>0.36              |                           | 0.44<br>0.44              |                                     | 0.52<br>0.52              |      |
| I <sub>IN</sub>  | Input<br>Leakage<br>Current    | 0 = V <sub>IN</sub> = 5.5 V  | 0 to 5.5            |                           |          | ±0.1                      |                           | ±1.0                      |                                     | ±1.0                      | μΑ   |
| I <sub>CC</sub>  | Quiescent<br>Supply<br>Current | V <sub>IN</sub> = 5.5 V or<br>GND  | 5.5                 |                           |          | 1.0                       |                           | 20                        |                                     | 40                        | μΑ   |
| I <sub>CCT</sub> | Quiescent<br>Supply<br>Current | V <sub>IN</sub> = 3.4 V  | 5.5                 |                           |          | 1.35                      |                           | 1.50                      |                                     | 1.65                      | mA   |
| I <sub>OPD</sub> | Output<br>Leakage<br>Current   | V <sub>OUT</sub> = 5.5 V   | 0.0                 |                           |          | 0.5                       |                           | 5.0                       |                                     | 10                        | μΑ   |

#### **AC ELECTRICAL CHARACTERISTICS** (Input $t_r = t_f = 3.0$ n)

|                    |   |                     | Test T <sub>A</sub> = 25 °C T <sub>A</sub> = +85°C |     | T <sub>A</sub> = 25 °C |      | T <sub>A</sub> = −55°C<br>to +125°C |      |     |      |      |
|--------------------|---|---------------------|--|-----|------------------------|------|-------------------------------------|------|-----|------|------|
| Symbol             | Parameter                                 | V <sub>CC</sub> (V) | Condition  | Min | Тур                    | Max  | Min                                 | Max  | Min | Max  | Unit |
| t <sub>PLH</sub> , | Propagation Delay,                        | 1.65 to 1.95        | C <sub>L</sub> = 15 pF                             |     |                        | 16.6 |                                     | 18.0 |     | 22.0 | ns   |
| t <sub>PHL</sub>   | Input A to Output ▼                       | 2.3 to 2.7          | C <sub>L</sub> = 15 pF                             |     |                        | 13.3 |                                     | 14.5 |     | 17.5 |      |
|                    |   |                     | C <sub>L</sub> = 50 pF                             |     |                        | 19.5 |                                     | 22.0 |     | 25.5 |      |
|                    |   | 3.0 to 3.6          | C <sub>L</sub> = 15 pF                             |     | 4.5                    | 10.0 |                                     | 11.0 |     | 13.0 |      |
|                    |   |                     | C <sub>L</sub> = 50 pF                             |     | 6.3                    | 13.5 |                                     | 15.0 |     | 17.5 |      |
|                    |   | 4.5 to 5.5          | C <sub>L</sub> = 15 pF                             |     | 3.5                    | 6.7  |                                     | 7.5  |     | 8.5  |      |
|                    |   |                     | C <sub>L</sub> = 50 pF                             |     | 4.3                    | 7.7  |                                     | 8.5  |     | 9.5  |      |
| C <sub>IN</sub>    | Input Capacitance                         |                     |  |     | 5                      | 10   |                                     | 10   |     | 10.0 | pF   |
| C <sub>PD</sub>    | Power Dissipation<br>Capacitance (Note 6) | 5.0                 |  |     | 12                     |      |                                     |      |     |      | pF   |

6.  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the dynamic operating current consumption without load. Average operating current can be obtained by the equation  $I_{CC(OPR)} = C_{PD} \bullet V_{CC} \bullet f_{in} + I_{CC}$ .  $C_{PD}$  is used to determine the no-load dynamic power consumption:  $P_D = C_{PD} \bullet V_{CC}^2 \bullet f_{in} + I_{CC} \bullet V_{CC}$ .

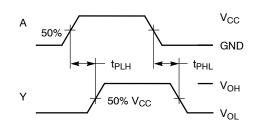
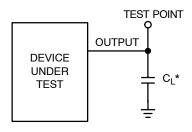


Figure 3. Switching Waveforms



\*Includes all probe and jig capacitance

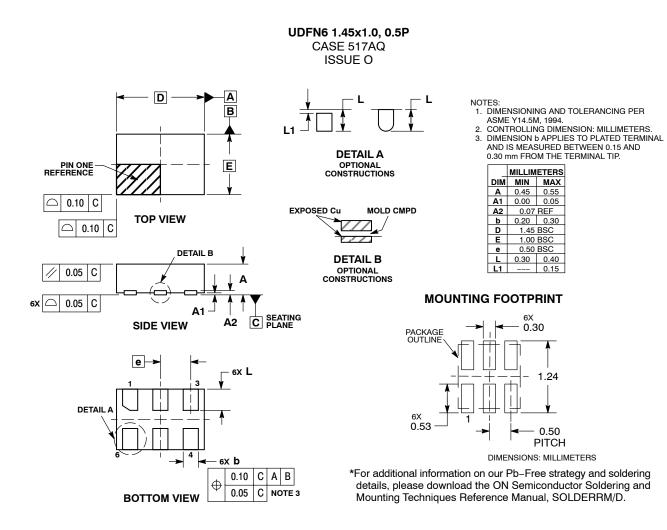
#### Figure 4. Test Circuit

#### **ORDERING INFORMATION**

| Device          | Package                               | Shipping <sup>†</sup> |
|-----------------|---------------------------------------|-----------------------|
| NLU1GT50MUTCG   | UDFN6, 1.2 x 1.0, 0.4P<br>(Pb–Free)   | 3000 / Tape & Reel    |
| NLU1GT50AMX1TCG | ULLGA6, 1.45 x 1.0, 0.5P<br>(Pb–Free) | 3000 / Tape & Reel    |
| NLU1GT50CMX1TCG | ULLGA6, 1.0 x 1.0, 0.35P<br>(Pb–Free) | 3000 / Tape & Reel    |
| NLU1GT50AMUTCG  | UDFN6, 1.45 x 1.0, 0.5P<br>(Pb-Free)  | 3000 / Tape & Reel    |
| NLU1GT50CMUTCG  | UDFN6, 1.0 x 1.0, 0.35P<br>(Pb-Free)  | 3000 / Tape & Reel    |

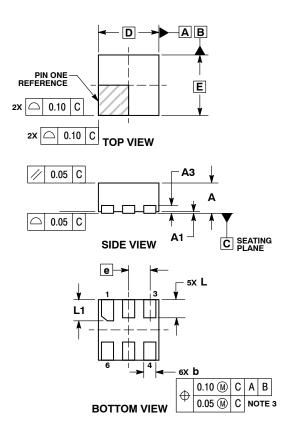
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

#### PACKAGE DIMENSIONS



#### PACKAGE DIMENSIONS

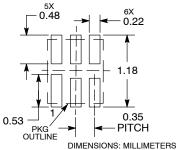
UDFN6 1.0x1.0, 0.35P CASE 517BX ISSUE O



- NOTES: 1. DIMENSIONING AND TOLERANCING PER
- DIMENSIONING AND TOLEHANGING FELL ASME Y14.5M, 1994.
  CONTROLLING DIMENSION: MILLIMETERS.
  DIMENSION & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.20 MM FROM TERMINAL TIP.
  PACKAGE DIMENSIONS EXCLUSIVE OF BURRS AND MOLD FLASH.

| BURH | BURRS AND MOLD FL |      |  |  |  |  |
|------|-------------------|------|--|--|--|--|
|      | MILLIMETERS       |      |  |  |  |  |
| DIM  | MIN               | MAX  |  |  |  |  |
| Α    | 0.45              | 0.55 |  |  |  |  |
| A1   | 0.00              | 0.05 |  |  |  |  |
| A3   | 0.13 REF          |      |  |  |  |  |
| b    | 0.12              | 0.22 |  |  |  |  |
| D    | 1.00              | BSC  |  |  |  |  |
| E    | 1.00              | BSC  |  |  |  |  |
| е    | 0.35 BSC          |      |  |  |  |  |
| L    | 0.25              | 0.35 |  |  |  |  |
| L1   | 0.30              | 0.40 |  |  |  |  |

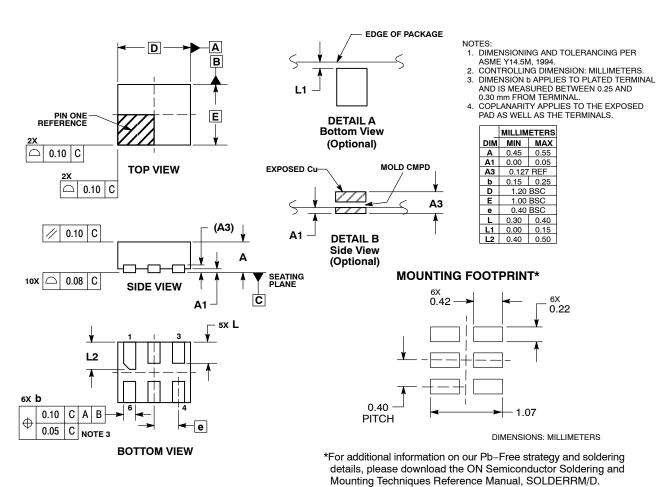
# RECOMMENDED SOLDERING FOOTPRINT\*



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

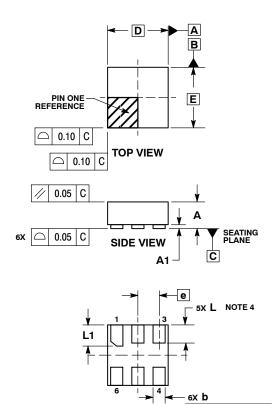
#### PACKAGE DIMENSIONS

UDFN6, 1.2x1.0, 0.4P CASE 517AA ISSUE D



#### PACKAGE DIMENSIONS

ULLGA6 1.0x1.0, 0.35P CASE 613AD **ISSUE A** 



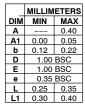
**BOTTOM VIEW** 

CAB

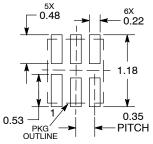
0.10

Φ 0.05 С NOTE 3 NOTES:

- NOTES: 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. 2. CONTROLLING DIMENSION: MILLIMETERS. 3. DIMENSION & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30 mm FROM THE TERMINAL TIP. 4. A MAXIMUM OF 0.05 PULL BACK OF THE PLATED TERMINAL FROM THE EDGE OF THE PACKAGE IS ALLOWED.



# MOUNTING FOOTPRINT SOLDERMASK DEFINED\*

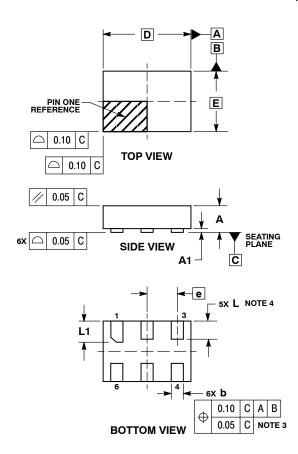


DIMENSIONS: MILLIMETERS

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### PACKAGE DIMENSIONS

ULLGA6 1.45x1.0, 0.5P CASE 613AF ISSUE A

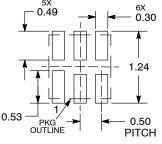


NOTES: 1. DIMENSIONING AND TOLERANCING PER ASME X14 5M 1994

- ASME Y14.5M, 1994. 2. CONTROLLING DIMENSION: MILLIMETERS. 3. DIMENSION 6 APPLIES TO PLATED TERMINAL
- DIMENSION & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30 mm FROM THE TERMINAL TIP.
   A MAXIMUM OF 0.05 PULL BACK OF THE
- PLATED TERMINAL FROM THE EDGE OF THE PACKAGE IS ALLOWED.

|     | MILLIMETERS |      |  |  |  |
|-----|-------------|------|--|--|--|
| DIM | MIN         | MAX  |  |  |  |
| Α   |             | 0.40 |  |  |  |
| A1  | 0.00        | 0.05 |  |  |  |
| b   | 0.15        | 0.25 |  |  |  |
| D   | 1.45 BSC    |      |  |  |  |
| E   | 1.00 BSC    |      |  |  |  |
| е   | 0.50 BSC    |      |  |  |  |
| L   | 0.25        | 0.35 |  |  |  |
| L1  | 0.30        | 0.40 |  |  |  |

#### MOUNTING FOOTPRINT SOLDERMASK DEFINED\*



DIMENSIONS: MILLIMETERS

\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MiniGate is a trademark of Semiconductor Components Industries, LLC (SCILLC).

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent-Marking.pdf</u>. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights or others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor hardles, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or

#### PUBLICATION ORDERING INFORMATION

#### LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303–675–2175 or 800–344–3860 Toll Free USA/Canada Fax: 303–675–2176 or 800–344–3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support: Depart 421 22 700 2010

Phone: 421 33 790 2910 Japan Customer Focus Center Phone: 81-3-5817-1050 ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

## **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Buffers & Line Drivers category:

Click to view products by ON Semiconductor manufacturer:

Other Similar products are found below :

LXV200-024SW 74AUP2G34FW3-7 HEF4043BP PI74FCT3244L MC74HCT365ADTR2G Le87401NQC Le87402MQC 028192B 042140C 051117G 070519XB NL17SZ07P5T5G NLU1GT126AMUTCG 74AUP1G17FW5-7 74LVC2G17FW4-7 CD4502BE 5962-8982101PA 5962-9052201PA 74LVC1G125FW4-7 NL17SH17P5T5G NL17SH125P5T5G NLV37WZ07USG RHRXH162244K1 74AUP1G34FW5-7 74AUP1G07FW5-7 74LVC2G126RA3-7 NLX2G17CMUTCG 74LVCE1G125FZ4-7 Le87501NQC 74AUP1G126FW5-7 TC74HC4050AP(F) 74LVCE1G07FZ4-7 NLX3G16DMUTCG NLX2G06AMUTCG NLVVHC1G50DFT2G NLU2G17AMUTCG LE87100NQC LE87290YQC LE87290YQCT LE87511NQC LE87511NQCT LE87557NQC LE87557NQCT LE87614MQC LE87614MQCT 74AUP1G125FW5-7 NLU2G16CMUTCG MC74LCX244MN2TWG NLV74VHC125DTR2G NL17SG126DFT2G